

T-30-13

HIGH SPEED, HIGH CURRENT SWITCHING APPLICATIONS.  
CHOPPER REGULATOR, DC-DC CONVERTER AND MOTOR  
DRIVE APPLICATIONS.

## FEATURES:

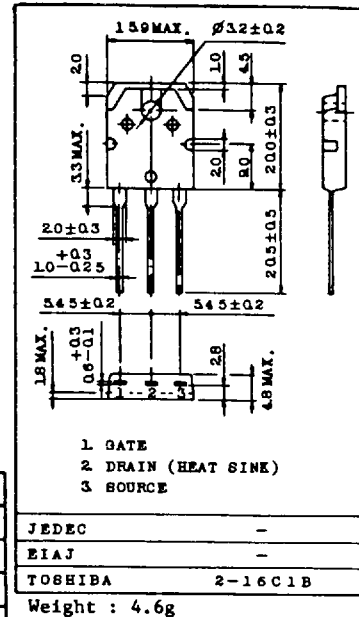
- Low Drain-Source ON Resistance :  $R_{DS(ON)}=0.070\Omega$ (Typ.)
- High Forward Transfer Admittance :  $|Y_{fs}|=12S$  (Typ.)
- Low Leakage Current :  $I_{GSS}=\pm 100nA$ (Max.) @  $V_{GS}=\pm 20V$   
 $I_{DSS}=250\mu A$  (Max.) @  $V_{DS}=200V$
- Enhancement-Mode :  $V_{th}=2.0\sim 4.0V$  @  $V_{DS}=10V, I_D=250\mu A$

MAXIMUM RATINGS ( $T_a=25^\circ C$ )

CHARACTERISTIC		SYMBOL	RATING	UNIT
Drain-Source Voltage		$V_{DSX}$	200	V
Drain-Gate Voltage ( $R_{GS}=20k\Omega$ )		$V_{DGR}$	200	V
Gate-Source Voltage		$V_{GSS}$	$\pm 20$	V
Drain Current	DC	$I_D$	30	A
	Pulse	$I_{DP}$	120	
Drain Power Dissipation ( $T_c=25^\circ C$ )		$P_D$	150	W
Channel Temperature		$T_{ch}$	150	$^\circ C$
Storage Temperature Range		$T_{stg}$	$-55\sim 150$	$^\circ C$

## INDUSTRIAL APPLICATIONS

Unit in mm



## THERMAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNIT
Thermal Resistance, Junction to Case	$R_{th(j-c)}$	0.83	$^\circ C/W$
Thermal Resistance, Junction to Ambient	$R_{th(j-a)}$	50	$^\circ C/W$
Maximum Lead Temperature for Soldering Purposes (1.6mm from case for 10 seconds)	$T_L$	300	$^\circ C$

YTFP250

T-39-13

## ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage Current		IGSS	VGS=±20V, VDS=0V	-	-	±100	nA
Drain Cut-off Current		IDSS	VDS=200V, VGS=0V	-	-	250	µA
Drain-Source Breakdown Voltage		V(BR)DSS	ID=250µA, VGS=0V	200	-	-	V
Gate Threshold Voltage		Vth	VDS=10V, ID=250µA	2.0	-	4.0	V
Forward Transfer Admittance		Yfs	VDS=10V, ID=16A	8	12	-	S
Drain-Source ON Resistance		RDS(ON)	ID=16A, VGS=10V	-	0.070	0.085	Ω
Input Capacitance		Ciss	VDS=10V, VGS=0V, f=1MHz	-	2100	2700	pF
Reverse Transfer Capacitance		Crss		-	600	900	
Output Capacitance		Coss		-	1400	2000	
Switching Time	Rise Time	tr	<p>10V 0 10µs VIN: tr, tf &lt; 5ns Duty ≤ 1% ID=16A VOUT VDD=100V</p>	-	35	70	ns
	Turn-on Time	ton		-	55	110	
	Fall Time	tf		-	30	60	
	Turn-off Time	toff		-	90	180	
Total Gate charge (Gate-Source Plus Gate-Drain)		Qg	ID=30A, VGS=10V	-	85	120	nC
Gate-Source Charge		Qgs	VDD=160V	-	40	-	
Gate-Drain ("Miller") Charge		Qgd		-	45	-	

## SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (Ta=25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Continuous Drain Reverse Current	IDR	--	-	-	30	A
Pulse Drain Reverse Current	IDRP	--	-	-	120	A
Diode Forward Voltage	VDSF	IDR=30A, VGS=0V	-	-	2.0	V
Reverse Recovery Time	trr	IDR=30A	-	500	-	ns
Reverse Recovered Charge	Qrr	dIDR/dt=100A/µs	-	4.2	-	µC